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10/036156
12/26/01

PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10036156	FILING DATE 12/26/2001	CLASS 438	SUBCLASS 592	GAU 2573 2642	EXAMINER CHEN
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**APPLICANTS: Park Dae; Cho Heung; Jim Kwan;

**CONTINUING DATA VERIFIED:

None

NOTE-DISCLAIMER
The term of this patent shall not extend
beyond the expiration date
of Pat. No. 6506676

** FOREIGN APPLICATIONS VERIFIED:
REPUBLIC OF KOREA 2000-85582 12/29/2000

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	
Foreign priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		ATTORNEY DOCKET NO	
35 USC 119 conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		29936/37830	
Verified and Acknowledged Examiners's initials <i>~</i>			
TITLE : Method of forming a metal gate in a semiconductor device			

U.S. DEPT. OF COM. / PAT. & TM. PTO-436L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED	
		Total Claims	Print Claim for O.G.
ISSUE FEE		DRAWING	
Amount Due	Date Paid	Sheets Drwg.	Figs. Drwg.
			Print Fig.
<input checked="" type="checkbox"/> TERMINAL DISCLAIMER		Application Examiner	
		PREPARED FOR ISSUE	
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